2N3903 is a Preferred Device

General Purpose Transistors

NPN Silicon

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCEO	40	Vdc
Collector-Base Voltage	VCBO	60	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	Vdc
Collector Current – Continuous	IC	200	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS (Note 1.)

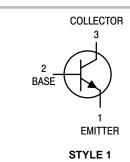
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	200	°C/W
Thermal Resistance, Junction to Case	R _θ JC	83.3	°C/W

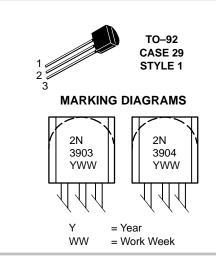
^{1.} Indicates Data in addition to JEDEC Requirements.



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ORDERING INFORMATION

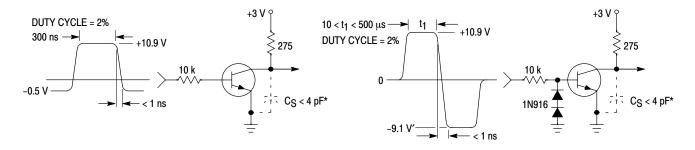
Device	Package	Shipping
2N3903	TO-92	5000 Units/Box
2N3903RLRM	TO-92	2000/Ammo Pack
2N3904	TO-92	5000 Units/Box
2N3904RLRA	TO-92	2000/Tape & Reel
2N3904RLRE	TO-92	2000/Tape & Reel
2N3904RLRM	TO-92	2000/Ammo Pack
2N3904RLRP	TO-92	2000/Ammo Pack
2N3904RL1	TO-92	2000/Tape & Reel
2N3904ZL1	TO-92	2000/Ammo Pack

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic			Symbol	Min	Max	Unit
OFF CHARACTER	RISTICS					
Collector–Emitter Br	eakdown Voltage (Note 2.) (I _C = 1.0 mAdc, I _B = 0	0)	V _(BR) CEO	40	_	Vdc
Collector-Base Brea	akdown Voltage ($I_C = 10 \mu Adc, I_E = 0$)		V(BR)CBO	60	-	Vdc
Emitter-Base Break	down Voltage (I _E = 10 μAdc, I _C = 0)		V(BR)EBO	6.0	_	Vdc
Base Cutoff Current	(V _{CE} = 30 Vdc, V _{EB} = 3.0 Vdc)		I _{BL}	_	50	nAdc
Collector Cutoff Curr	rent (V _{CE} = 30 Vdc, V _{EB} = 3.0 Vdc)		ICEX	_	50	nAdc
ON CHARACTERI			<u> </u>		1	
DC Current Gain (No (I _C = 0.1 mAdc, V ₀		2N3903	hFE	20	_	-
$(I_C = 1.0 \text{ mAdc}, V_0)$		2N3904 2N3903		40 35	_ _	
$(I_C = 10 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$		2N3904 2N3903 2N3904			150 300	
$(I_C = 50 \text{ mAdc}, V_C)$	CE = 1.0 Vdc)	2N3903		30	-	
(I _C = 100 mAdc, V	'CE = 1.0 Vdc)	2N3904 2N3903 2N3904		60 15 30	_ _ _	
Collector–Emitter Sa (I _C = 10 mAdc, I _B (I _C = 50 mAdc, I _B			VCE(sat)	_ _	0.2 0.3	Vdc
Base–Emitter Saturation Voltage (Note 2.) (I _C = 10 mAdc, I _B = 1.0 mAdc) (I _C = 50 mAdc, I _B = 5.0 mAdc)			V _{BE} (sat)	0.65	0.85 0.95	Vdc
SMALL-SIGNAL (CHARACTERISTICS		<u> </u>		1	1
Current–Gain – Band (I _C = 10 mAdc, V _C	dwidth Product CE = 20 Vdc, f = 100 MHz)	2N3903 2N3904	fΤ	250 300	_ _	MHz
Output Capacitance	(V _{CB} = 5.0 Vdc, I _E = 0, f = 1.0 MHz)		C _{obo}	_	4.0	pF
	/EB = 0.5 Vdc, I _C = 0, f = 1.0 MHz)		C _{ibo}		8.0	pF
Input Impedance ($V_{EB} = 0.5 \text{ Vdc}$, $I_{C} = 0, I = 1.0 \text{ MHz}$) Input Impedance ($I_{C} = 1.0 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$, $f = 1.0 \text{ kHz}$)		2N3903 2N3904	h _{ie}	1.0 1.0	8.0 10	kΩ
Voltage Feedback Ratio (I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)		2N3903 2N3904	h _{re}	0.1 0.5	5.0 8.0	X 10 ⁻²
Small–Signal Current Gain (I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)		2N3903 2N3904	h _{fe}	50 100	200 400	-
Output Admittance (I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)		h _{oe}	1.0	40	μmhos	
Noise Figure (I _C = 100 μ Adc, V _{CE} = 5.0 Vdc, R _S = 1.0 k Ω , f = 1.0 kHz)		2N3903 2N3904	NF	_ 	6.0 5.0	dB
SWITCHING CHAI	RACTERISTICS					
Delay Time $(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc}, \\ I_{C} = 10 \text{ mAdc}, I_{B1} = 1.0 \text{ mAdc})$			t _d	_	35	ns
			t _r	_	35	ns
Storage Time	$(V_{CC} = 3.0 \text{ Vdc}, I_{C} = 10 \text{ mAdc}, I_{B1} = I_{B2} = 1.0 \text{ mAdc})$	2N3903 2N3904	t _S	_ _	175 200	ns
Fall Time					1	1

^{2.} Pulse Test: Pulse Width $\leq 300 \,\mu s$; Duty Cycle $\leq 2\%$.



* Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit

Figure 2. Storage and Fall Time Equivalent Test Circuit

TYPICAL TRANSIENT CHARACTERISTICS

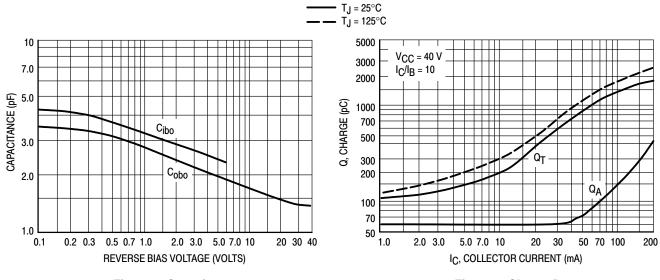
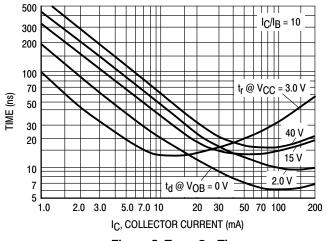


Figure 3. Capacitance

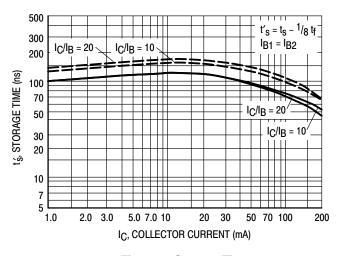
Figure 4. Charge Data



 $V_{CC} = 40 V$ 300 IC/IB = 10200 100 t_r, RISE TIME (ns) 70 50 30 20 10 5 2.0 3.0 1.0 5.0 7.0 10 20 30 50 70 100 200 IC, COLLECTOR CURRENT (mA)

Figure 5. Turn-On Time

Figure 6. Rise Time



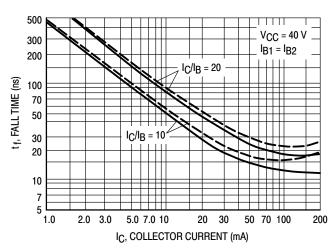
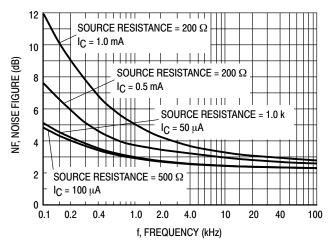


Figure 7. Storage Time

Figure 8. Fall Time

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$



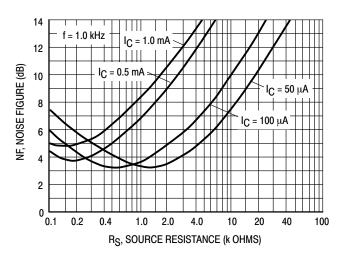


Figure 9.

Figure 10.

h PARAMETERS

(VCE = 10 Vdc, f = 1.0 kHz, $T_A = 25^{\circ}\text{C}$)

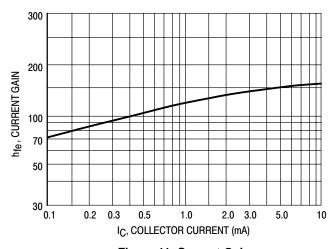


Figure 11. Current Gain

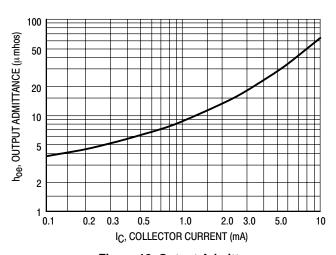


Figure 12. Output Admittance

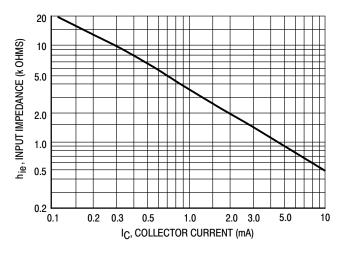


Figure 13. Input Impedance

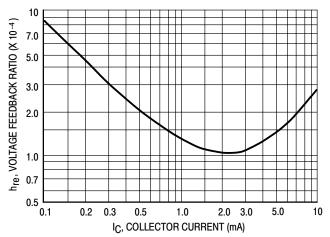


Figure 14. Voltage Feedback Ratio

TYPICAL STATIC CHARACTERISTICS

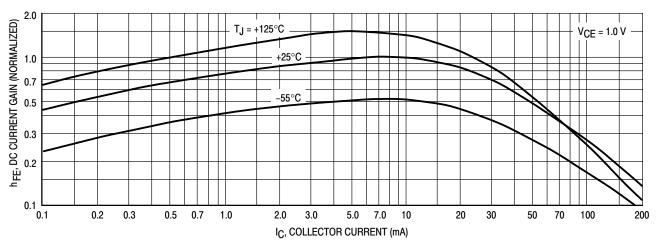


Figure 15. DC Current Gain

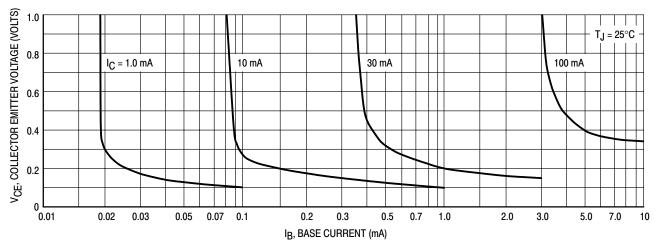


Figure 16. Collector Saturation Region

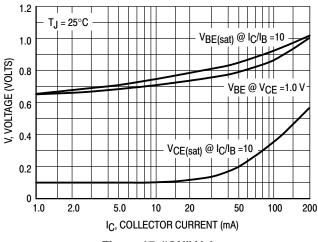


Figure 17. "ON" Voltages

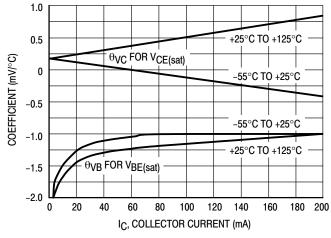
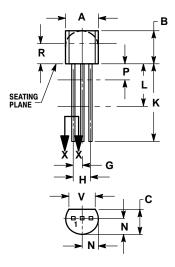


Figure 18. Temperature Coefficients

PACKAGE DIMENSIONS

TO-92 TO-226AA CASE 29-11 **ISSUE AL**





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
V	0.135		3 //3		

STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 14:
PIN 1. EMITTER
2. COLLECTOR
3. BASE

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